## FORM PTO-1449 (MODIFIED) ATTY DOCKET NO. SERIAL NO. LIST OF PATENTS AND PUBLICATIONS 67,200-1247 To Be Assigned FOR APPLICANT'S INFORMATION Kuo-Chi Tu Applicant: DISCLOSURE STATEMENT FILING DATE **GROUP** Unknown Filed Herewith (Use several sheets if necessary) REFERENCE DESIGNATION **U.S. PATENT DOCUMENTS EXAMINER DOCUMENT** SUB **FILING CLASS** DATE INITIAL NO. **CLASS** DATE NAME AA 5,360,753 11/1994 Park et al AB 12/1997 Chan et al 5,696,021 Rajeevakumar AC 5,930,107 07/1999 AD 6,232,202B1 05/2001 Hong ΑE 6,256,248B1 07/2001 Leung ΑF 6,420,226B1 07/2002 Chen et al 6,468,855B2 10/2002 Leung et al AG

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	AK						
	AL						
	AM						
	AN						

OTHER ART (including Author, Title, Date, pertinent pages, etc.)

		"A 130 nm Generation High Density Etox™ Flash Memory Technology", Kenney, IEEE, IEDM 2001, pp. 41-44.
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## **EXAMINER**

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6,573,548B2

## **DATE CONSIDERED**

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to application.